## **Switch-mode Schottky Power Rectifier**

#### **DPAK Power Surface Mount Package**

The NRVBD1035CTL employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State of the art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies, free wheeling diode and polarity protection diodes.

#### **Features**

- Highly Stable Oxide Passivated Junction
- Guardring for Stress Protection
- Matched Dual Die Construction –
   May be Paralleled for High Current Output
- High dv/dt Capability
- Short Heat Sink Tap Manufactured Not Sheared
- Very Low Forward Voltage Drop
- Epoxy Meets UL 94 V-0 @ 0.125 in
- This is a Pb-Free Device

#### **Mechanical Characteristics:**

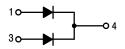
- Case: Epoxy, Molded
- Weight: 0.4 Gram (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



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# SCHOTTKY BARRIER RECTIFIER 10 AMPERES 35 VOLTS





DPAK CASE 369C

#### **MARKING DIAGRAM**



A = Assembly Location

Y = Year
WW = Work Week
B1035CL = Device Code
G = Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### **MAXIMUM RATINGS**

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	35	V
Average Rectified Forward Current (At Rated $V_R$ , $T_C = 115^{\circ}C$ )	Per Leg Per Package	Io	5.0 10	А
Peak Repetitive Forward Current (At Rated V <sub>R</sub> , Square Wave, 20 kHz, T <sub>C</sub> = 115°C)	Per Leg	I <sub>FRM</sub>	10	А
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, sir	Per Package ngle phase, 60 Hz)	I <sub>FSM</sub>	50	А
Storage / Operating Case Temperature		T <sub>stg,</sub> T <sub>c</sub>	-55 to +150	°C
Operating Junction Temperature (Note 1)		TJ	-55 to +150	°C
Voltage Rate of Change (Rated V <sub>R</sub> , T <sub>J</sub> = 25°C)		dv/dt	10,000	V/μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Case	Per Leg	$R_{ heta JC}$	3.0	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	Per Leg	$R_{ heta JA}$	137	°C/W

#### **ELECTRICAL CHARACTERISTICS**

Maximum Instantaneous Forward Voltage (Note 3) (See Figure 2) $I_F = 5 \text{ Amps, } T_J = 25^{\circ}\text{C}$ $I_F = 5 \text{ Amps, } T_J = 100^{\circ}\text{C}$ $I_F = 10 \text{ Amps, } T_J = 25^{\circ}\text{C}$ $I_F = 10 \text{ Amps, } T_J = 100^{\circ}\text{C}$	Per Leg	V <sub>F</sub>	0.47 0.41 0.56 0.55	V
Maximum Instantaneous Reverse Current (Note 3) (See Figure 4) $ (V_R = 35 \text{ V}, T_J = 25^{\circ}\text{C}) $ $ (V_R = 35 \text{ V}, T_J = 100^{\circ}\text{C}) $ $ (V_R = 17.5 \text{ V}, T_J = 25^{\circ}\text{C}) $ $ (V_R = 17.5 \text{ V}, T_J = 100^{\circ}\text{C}) $	Per Leg	I <sub>R</sub>	2.0 30 0.20 5.0	mA

<sup>2.</sup> Rating applies when using minimum pad size, FR4 PC Board

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NRVBD1035CTLT4G	DPAK (Pb-Free)	2500 Units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

<sup>3.</sup> Pulse Test: Pulse Width ≤ 250 µs, Duty Cycle ≤ 2.0%

#### **TYPICAL CHARACTERISTICS**

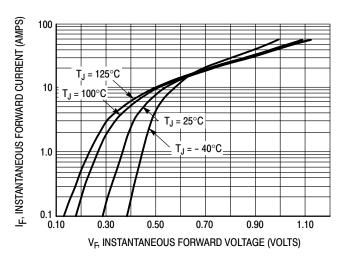
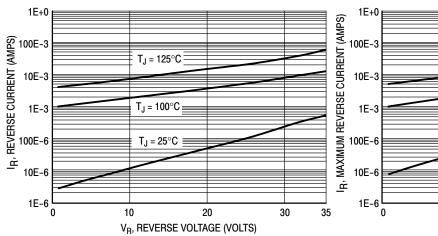


Figure 1. Typical Forward Voltage Per Leg

Figure 2. Maximum Forward Voltage Per Leg



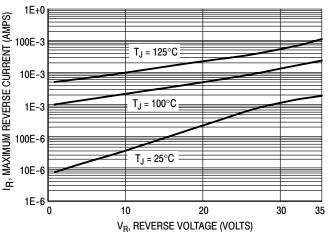


Figure 3. Typical Reverse Current Per Leg

Figure 4. Maximum Reverse Current Per Leg

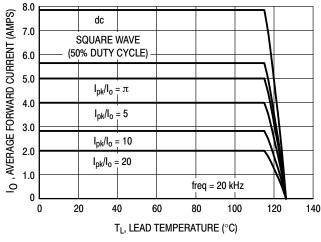


Figure 5. Current Derating Per Leg

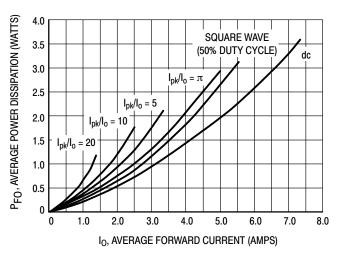


Figure 6. Forward Power Dissipation Per Leg

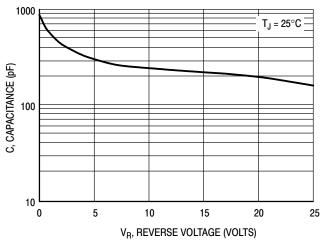


Figure 7. Capacitance Per Leg

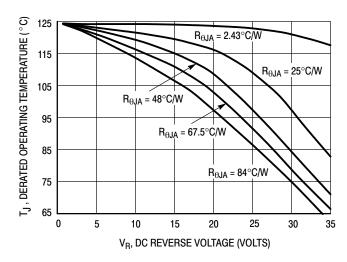


Figure 8. Typical Operating Temperature
Derating Per Leg \*

r(t) = thermal impedance under given conditions,

Pf = forward power dissipation, and

Pr = reverse power dissipation

This graph displays the derated allowable  $T_J$  due to reverse bias under DC conditions only and is calculated as  $T_J = T_{Jmax} - r(t)Pr$ , where r(t) = Rthja. For other power applications further calculations must be performed.

<sup>\*</sup> Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of  $T_J$  therefore must include forward and reverse power effects. The allowable operating  $T_J$  may be calculated from the equation:  $T_J = T_{Jmax} - r(t) (Pf + Pr) \text{ where}$ 

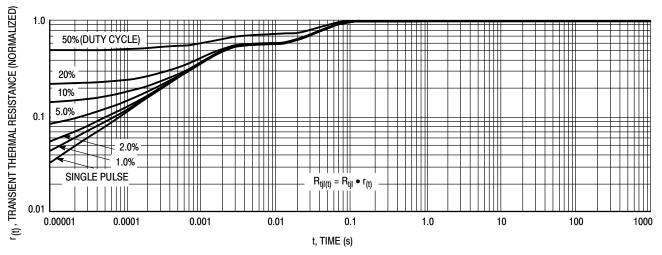


Figure 9. Thermal Response Junction to Case (Per Leg)

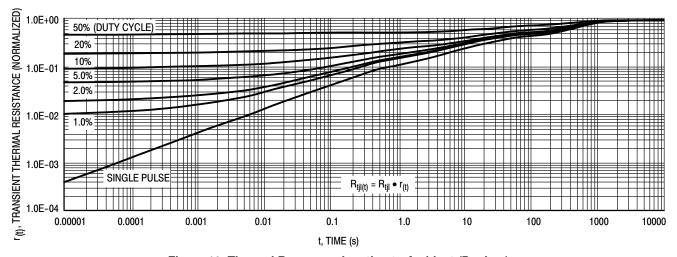
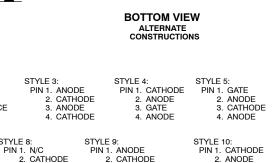


Figure 10. Thermal Response Junction to Ambient (Per Leg)



#### **DPAK (SINGLE GAUGE)** CASE 369C **ISSUE F** SCALE 1:1 Α <-b3 В L3 Z ۩ **DETAIL A** Ш NOTE 7 C → **BOTTOM VIEW** h2 e SIDE VIEW ⊕ 0.005 (0.13) M C **TOP VIEW** Z H L2 GAUGE C SEATING PLANE



3. CATHODE 4. ANODE

3. RESISTOR ADJUST 4. CATHODE

#### **SOLDERING FOOTPRINT\***

3. ANODE 4. CATHODE

STYLE 8:

Α1

PIN 1. GATE 2. DRAIN

SOURCE

4. DRAIN

STYLE 2:

PIN 1. GATE 2. COLLECTOR

3. EMITTER 4. COLLECTOR

**DETAIL A** ROTATED 90° CW

STYLE 7:

STYLE 1:

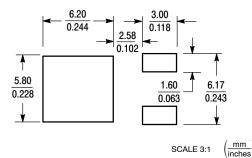
STYLE 6:

PIN 1. MT1 2. MT2

3. GATE 4. MT2

PIN 1. BASE 2. COLLECTOR 3. EMITTER

4. COLLECTOR



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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**DATE 21 JUL 2015** 

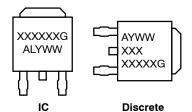
#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCHES.
- 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- MENSIONS b3, L3 and Z.
  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
  5. DIMENSIONS D AND E ARE DETERMINED AT THE
- OUTERMOST EXTREMES OF THE PLASTIC BODY.

  6. DATUMS A AND B ARE DETERMINED AT DATUM
- 7. OPTIONAL MOLD FEATURE.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
е	0.090 BSC		2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114 REF		2.90	REF
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

#### **GENERIC MARKING DIAGRAM\***



XXXXXX = Device Code = Assembly Location Α L = Wafer Lot Υ = Year

WW = Work Week = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	DPAK (SINGLE GAUGE)		PAGE 1 OF 1	

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